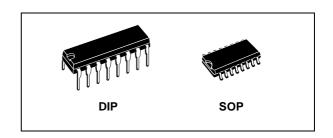


RIPPLE-CARRY BINARY COUNTER/DIVIDERS 14 STAGE

- MEDIUM SPEED OPERATION: 16MHz (Typ.) at V_{DD} = 10V
- FULLY STATIC OPERATION
- COMMON RESET
- BUFFERED INPUTS AND OUTPUTS
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I_I = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
- 100% TESTED FOR QUIESCENT CURRENT



HCF4020B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. HCF4020B is a ripple carry binary counter. All counter stages are master-slave flip-flops. The state of a counter advances one count on the



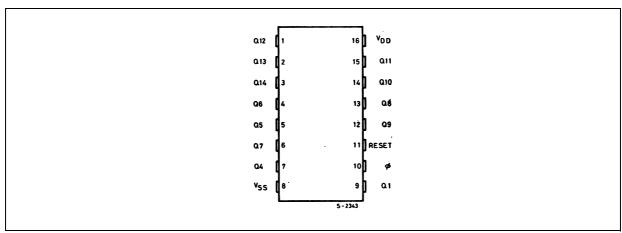
ORDER CODES

PACKAGE	TUBE	T&R
DIP	HCF4020BEY	
SOP	HCF4020BM1	HCF4020M013TR

negative transition of each input pulse; a high level on the RESET line resets the counter to its all zeros stage. Schmitt trigger action on the input pulse line permits unlimited clock rise and fall times

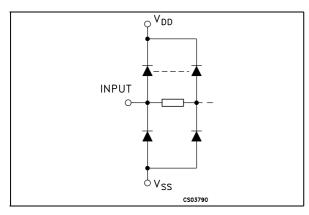
All inputs and outputs are buffered.

PIN CONNECTION



March 2004 1/11

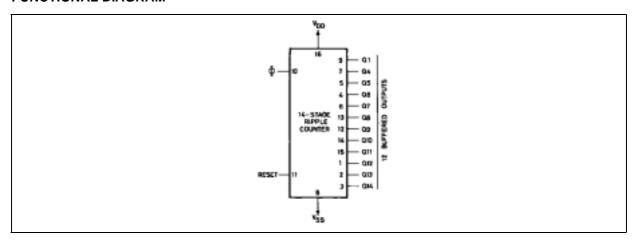
IINPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN N°	SYMBOL	NAME AND FUNCTION
9, 7, 5, 4, 6, 13, 12, 14, 15, 1, 2, 3	Q1, Q4 to Q14	14 Buffered Outputs
11	RESET	Reset Input
10	Φ	Input Pulses
8	V_{SS}	Negative Supply Voltage
16	V_{DD}	Positive Supply Voltage

FUNCTIONAL DIAGRAM

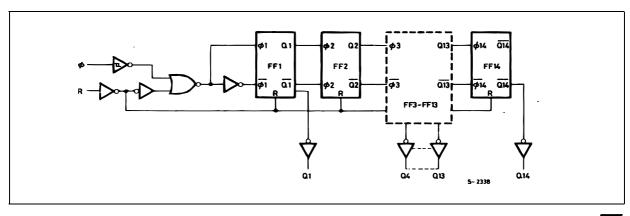


TRUTH TABLE

Φ	RESET	OUTPUT STATE
X	Н	ALL OUTPUTS = "L"
	L	NO CHANGE
	L	ADVANCE TO NEXT STATE

X : Don't Care

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	-0.5 to +22	V
VI	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V _I	Input Voltage	0 to V _{DD}	V
T _{op}	Operating Temperature	-55 to 125	°C

DC SPECIFICATIONS

		Test Condition			Value								
Symbol Parameter		VI	v _o	ΙΙ _Ο Ι	V _{DD}	T _A = 25°C		С	-40 to 85°C		-55 to 125°C		Unit
		(V)	(V)	(μA)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	0/5			5		0.04	5		150		150	
		0/10			10		0.04	10		300		300	μΑ
		0/15			15		0.04	20		600		600	μΛ
		0/20			20		0.08	100		3000		3000	
V _{OH}	High Level Output	0/5		<1	5	4.95			4.95		4.95		
	Voltage	0/10		<1	10	9.95			9.95		9.95		V
		0/15		<1	15	14.95			14.95		14.95		
V_{OL}	Low Level Output	5/0		<1	5			0.05		0.05		0.05	
	Voltage	10/0		<1	10			0.05		0.05		0.05	V
		15/0		<1	15			0.05		0.05		0.05	
V_{IH}	High Level Input		0.5/4.5	<1	5	3.5			3.5		3.5		
	Voltage		1/9	<1	10	7			7		7		V
			1.5/13.5	<1	15	11			11		11		
V_{IL}	Low Level Input		4.5/0.5	<1	5			1.5		1.5		1.5	
	Voltage		9/1	<1	10			3		3		3	V
			13.5/1.5	<1	15			4		4		4	
I _{OH}	Output Drive	0/5	2.5	<1	5	-1.36	-3.2		-1.1		-1.1		
	Current	0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		mΑ
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		ША
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4		
l _{OL}	Output Sink	0/5	0.4	<1	5	0.44	1		0.36		0.36		
	Current	0/10	0.5	<1	10	1.1	2.6		0.9		0.9		mΑ
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
I _I	Input Leakage Current	0/18	Any In	put	18		±10 ⁻⁵	±0.1		±1		±1	μΑ
C _I	Input Capacitance		Any In	put			5	7.5					pF

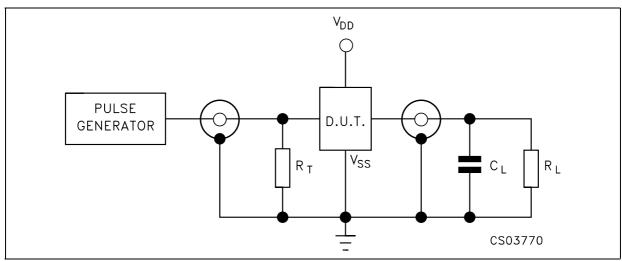
The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} =5V, 2V min. with V_{DD} =10V, 2.5V min. with V_{DD} =15V

$\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \ (T_{amb} = 25 ^{\circ}\text{C}, \ C_{L} = 50 \text{pF}, \ R_{L} = 200 \text{K}\Omega, \ t_{r} = t_{f} = 20 \ \text{ns})$

			Test Condition	,	Value (*)		
Symbol	mbol Parameter			Min.	Тур.	Max.	
		INPUT-	PULSE OPERATION		1	1	
t _{PLH} t _{PHL}	(∅ to Q1 Out)	5			180	360	
		10			80	160	ns
		15			65	130]
t _{PLH} t _{PHL}	Propagation Delay Time	5			100	200	
	(Qn to Qn+1)	10			40	80	ns
	15			30	60	1	
t _{THL} t _{TLH}	Transition Time	5			100	200	
		10			50	100	ns
	15			40	80	1	
t _W	t _W Minimum Input Pulse Width	5			70	140	
		10			30	60	ns
		15			20	40	1
t _r , t _f	Input Pulse Rise and Fall	5					
	Time	10		ı	unlimited		μs
		15					
f _{max}	Maximum Clock Input	5		3.5	7		
	Frequency	10		8	16		MHz
		15		12	24		1
		RES	SET OPERATION	•		•	
t _{PHL}	Propagation Delay Time	5			140	280	
		10			60	120	ns
		15			50	100	
t _W	Minimum Reset Pulse	5			100	200	
	Width	10			40	80	ns
		15			30	60	
t _{REM}	Reset Removal Time	5			175	350	
		10			75	150	ns
		15			50	100	

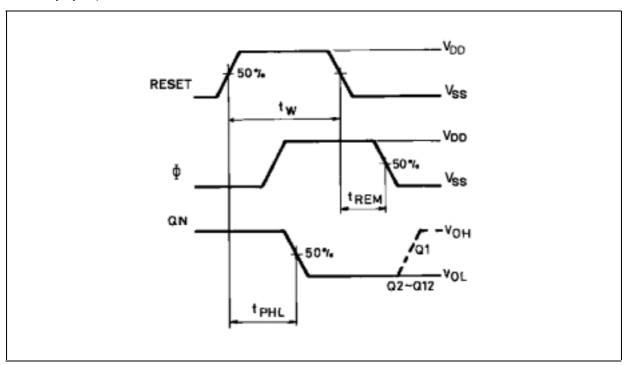
^(*) Typical temperature coefficient for all $V_{\mbox{\scriptsize DD}}$ value is 0.3%/°C.

TEST CIRCUIT

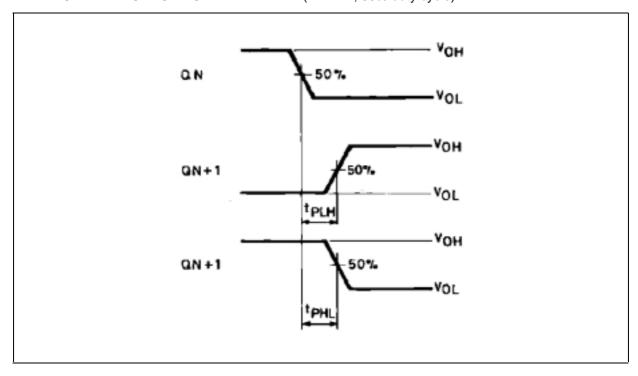


 C_L = 50pF or equivalent (includes jig and probe capacitance) R_L = 200K Ω R_T = Z_{OUT} of pulse generator (typically 50 Ω)

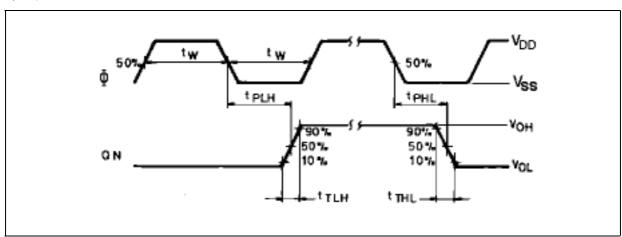
WAVEFORM 1: MINIMUM PULSE WIDTH (RESET) AND REMOVAL TIME (RESET TO Φ) (f=1MHz; 50% duty cycle)



WAVEFORM 2: PROPAGATION DELAY TIME (f=1MHz; 50% duty cycle)

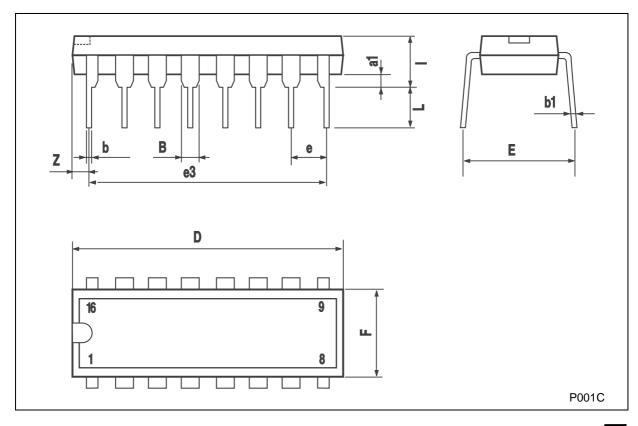


WAVEFORM 3: PROPAGATION DELAY TIME, MINIMUM PULSE WIDTH (Φ **)** (f=1MHz; 50% duty cycle)



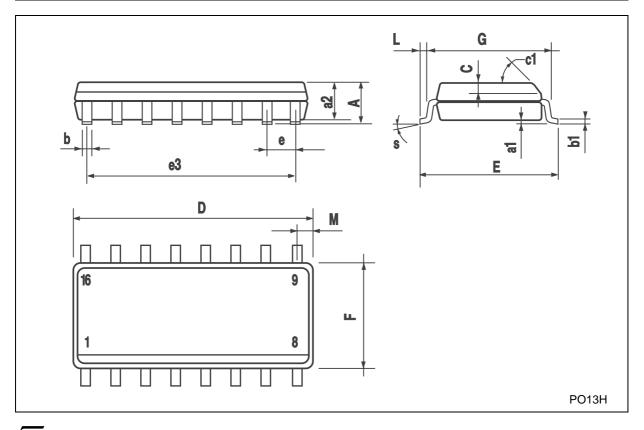
Plastic DIP-16 (0.25) MECHANICAL DATA

DIM		mm.		inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
a1	0.51			0.020			
В	0.77		1.65	0.030		0.065	
b		0.5			0.020		
b1		0.25			0.010		
D			20			0.787	
Е		8.5			0.335		
е		2.54			0.100		
e3		17.78			0.700		
F			7.1			0.280	
I			5.1			0.201	
L		3.3			0.130		
Z			1.27			0.050	



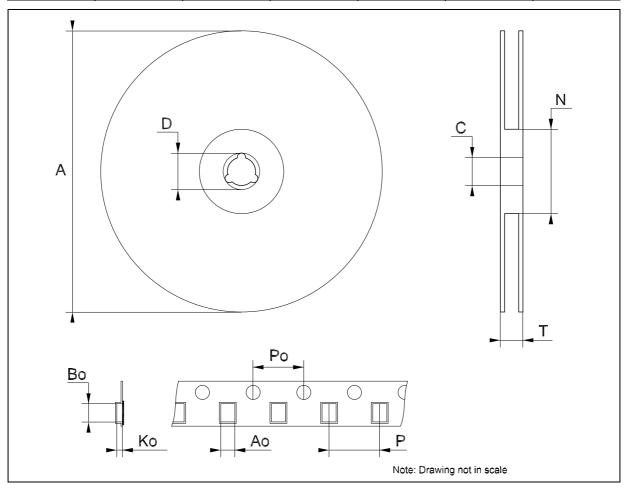
SO-16 MECHANICAL DATA

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α			1.75			0.068		
a1	0.1		0.2	0.004		0.008		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1			45°	(typ.)		•		
D	9.8		10	0.385		0.393		
Е	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		8.89			0.350			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
М			0.62			0.024		
S	8		° (r	max.)	1			



Tape & Reel SO-16 MECHANICAL DATA

DIM		mm.		inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.45		6.65	0.254		0.262
Во	10.3		10.5	0.406		0.414
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



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